

1. General description

WMS20N300SK is a high performance super logic level N-channel MOSFET in SOT23 package, which utilizes advanced Trench MOSFET technology to provide low $R_{DS(on)}$ and gate charge. It is designed and qualified in a wide range of industrial and consumer applications.



2. Features and benefits

- Advance High Cell Density Trench Technology
- Low $R_{DS(on)}$ to Minimize Conduction Losses
- Low Capacitance to Minimize Switching Losses
- Optimized Gate Charge to Minimize Driver Losses
- RoHS Compliant, Halogen Free and Lead Free

3. Applications

- Load Switch
- General PWM Applications

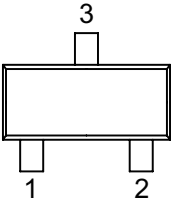
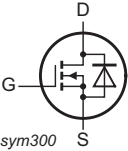
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V _{DS}	drain-source voltage			20			V
V _{GS}	gate-source voltage			±10			V
I _D	continuous drain current	V _{GS} = 4.5 V; T _a = 25 °C		5.4			A
P _{tot}	power dissipation	T _a = 25 °C		1.4			W
T _J	junction temperature			-55 to 150			°C
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
R _{DS(on)}	drain-source on-state resistance	V _{GS} = 4.5 V, I _D = 5.4 A		-	23	30	mΩ
		V _{GS} = 2.5 V, I _D = 3 A		-	30	45	mΩ
Dynamic characteristics							
Q _{G(tot)}	total gate charge	I _D = 5.4 A; V _{DS} = 10 V; V _{GS} = 4.5 V		-	4.5	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	S	source		
3	D	drain		

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WMS20N300SK	SOT23	WMS20N300SKX	Reel	3000	SOT23L	22-Aug-2022

7. Marking

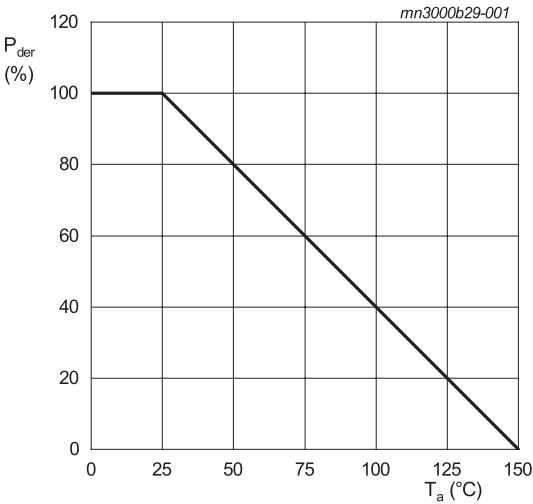
Table 4. Marking codes

Type number	Marking codes
WMS20N300SK	AA

8. Limiting values

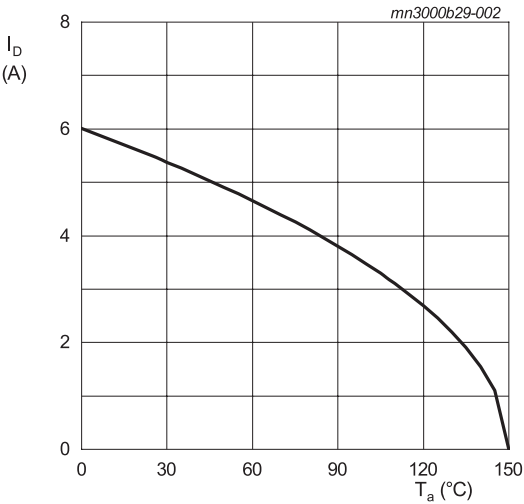
Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{DS}	drain-source voltage			20	V
V _{GS}	gate-source voltage			±10	V
I _D	continuous drain current	V _{GS} = 4.5 V; T _a = 25 °C		5.4	A
		V _{GS} = 4.5 V; T _a = 70 °C		4.3	A
I _{DM}	pulsed drain current	t _p = 10 μs; T _a = 25 °C		21.6	A
P _{tot}	power dissipation	T _a = 25 °C		1.4	W
T _{stg}	storage temperature			-55 to 150	°C
T _j	junction temperature			-55 to 150	°C



$$P_{\text{der}} = (P_{\text{tot}} / P_{\text{tot}(25\text{ °C})}) \times 100\%$$

Fig. 1. Normalized total power dissipation as a function of ambient temperature



V_{GS} = 4.5 V

Fig. 2. Continuous Drain Current as a function of ambient temperature

9. Thermal & Mechanical characteristics

Table 6. Thermal & Mechanical characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	$t \leq 10s$	[1]	-	72	90	K/W
		in free air	[1]	-	95	120	K/W

[2] Surface mount on FR4 board of 1 inch², 1 oz copper.

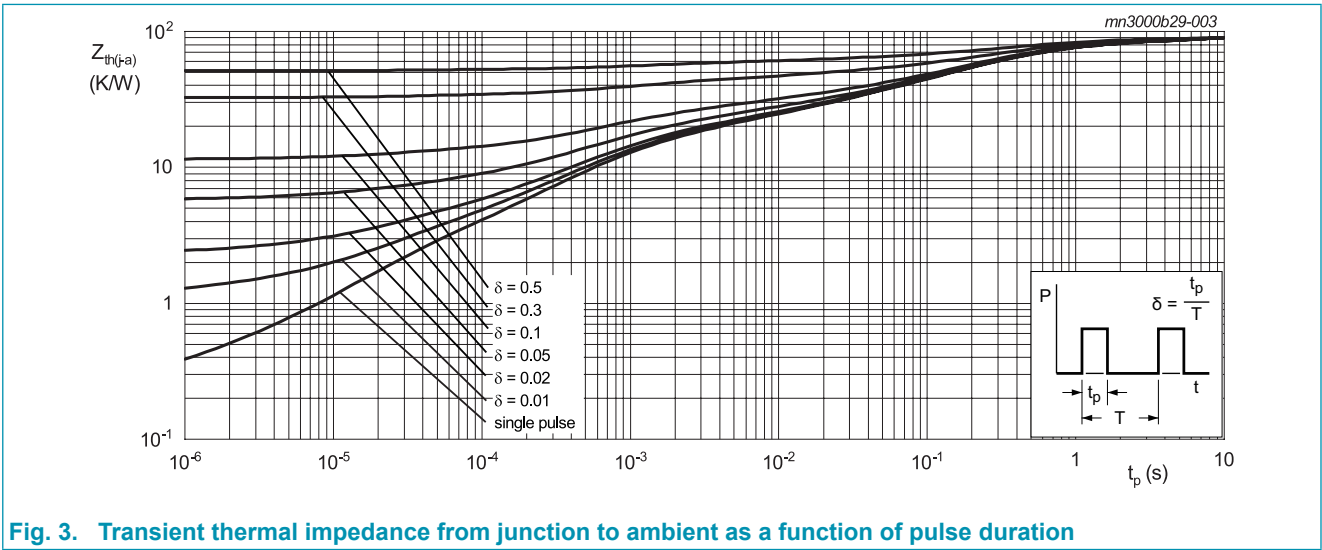


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration

10. Characteristics

Table 7. Characteristics
 $T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V		20	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 250 μA; V _{DS} = V _{GS}		0.45	0.7	1.1	V
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V		-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 125 °C		-	-	10	μA
I _{GSS}	gate leakage current	V _{GS} = ±10 V; V _{DS} = 0 V		-	-	±100	nA
R _{DS(on)}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 5.4 A		-	23	30	mΩ
		V _{GS} = 2.5 V; I _D = 3 A		-	30	45	mΩ
R _G	gate resistance	f = 1 MHz		-	4.2	-	Ω
Dynamic characteristics							
Q _{G(tot)}	total gate charge	I _D = 5.4 A; V _{DS} = 10 V; V _{GS} = 4.5 V		-	4.5	-	nC
Q _{GS}	gate-source charge			-	0.8	-	nC
Q _{GD}	gate-drain charge			-	1.3	-	nC
C _{iss}	input capacitance	V _{DS} = 10 V; V _{GS} = 0 V; f = 1 MHz		-	319	-	pF
C _{oss}	output capacitance			-	66	-	pF
C _{rss}	reverse transfer capacitance			-	58	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 10 V; V _{GS} = 4.5 V; R _G = 6 Ω; I _D = 5.4 A		-	7.0	-	ns
t _r	rise time			-	13	-	ns
t _{d(off)}	turn-off delay time			-	25	-	ns
t _f	fall time			-	12	-	ns
Source-drain diode							
V _{SD}	source-drain voltage	V _{GS} = 0 V; I _S = 1 A		-	0.7	1	V
		V _{GS} = 0 V; I _S = 1 A; T _j = 125 °C		-	0.57	-	V
I _S	body-diode continuous current	T _a = 25 °C		-	-	2	A
t _{rr}	reverse recovery time	V _{GS} = 0 V; I _S = 5.4 A; di/dt = 100 A/μs		-	9.4	-	ns
Q _{rr}	reverse recovered charge			-	2.7	-	nC
I _{rrm}	reverse recovery current			-	0.5	-	A

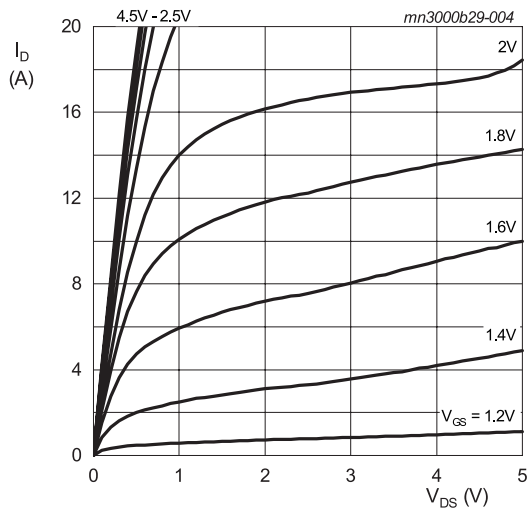


Fig. 4. Drain current as a function of drain-source voltage; typical values

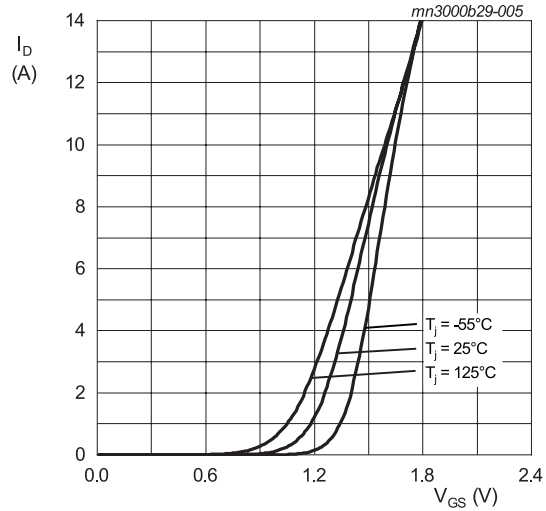


Fig. 5. Drain current as a function of gate-source voltage; typical values

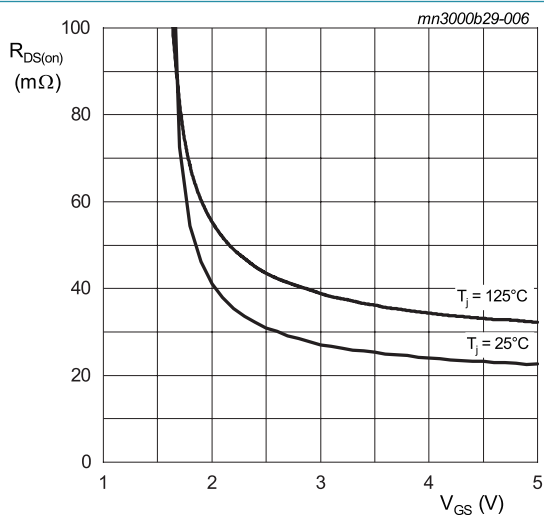


Fig. 6. Drain-source on-state resistance as a function of gate-source voltage; typical values

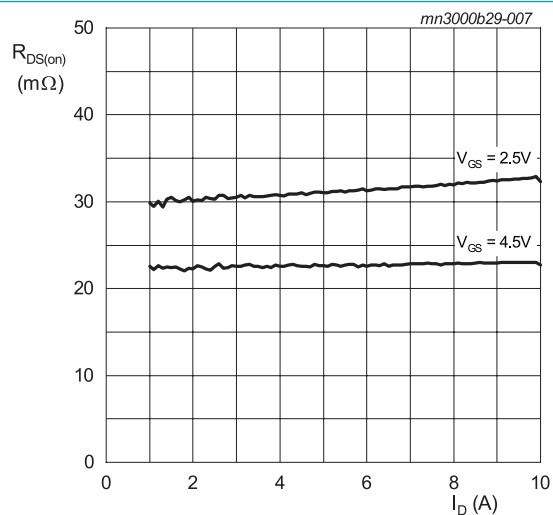
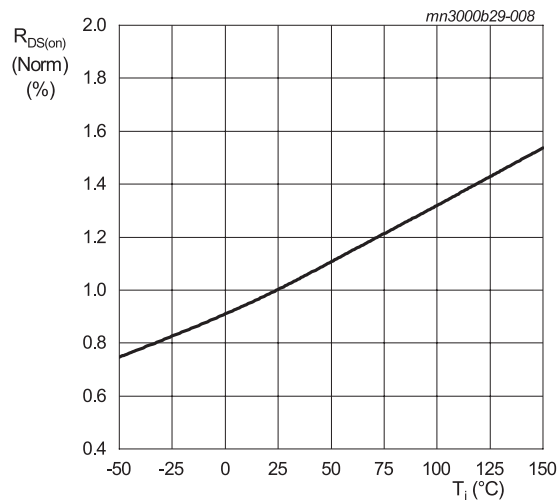
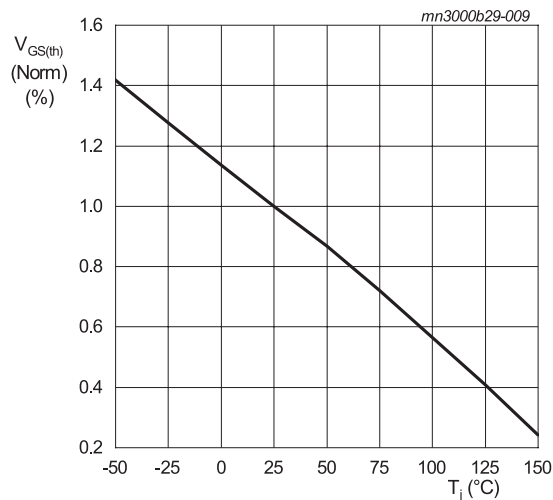


Fig. 7. Drain-source on-state resistance as a function of drain current; typical values



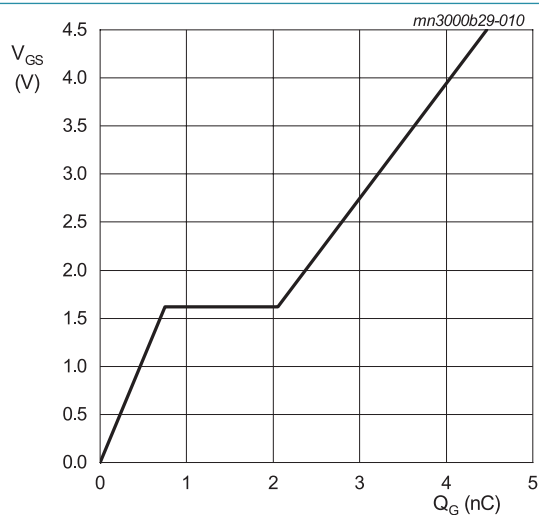
$V_{GS} = 4.5 \text{ V}; I_D = 5.4 \text{ A}$

Fig. 8. Normalized drain-source on-state resistance as a function of junction temperature



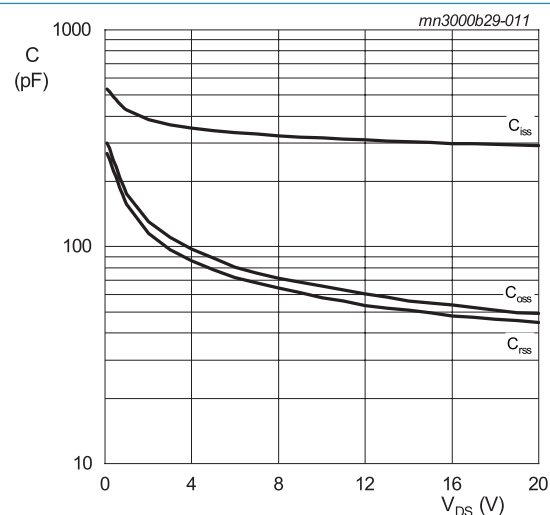
$V_{GS} = V_{GS(th)}; I_D = 250 \mu\text{A}$

Fig. 9. Normalized gate-source threshold voltage as a function of junction temperature



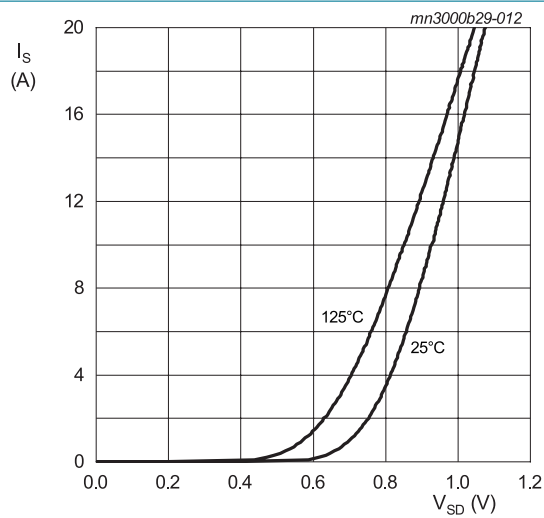
$I_D = 5.4 \text{ A}; V_{DS} = 10 \text{ V}$

Fig. 10. Gate-source voltage as a function of gate charge; typical values



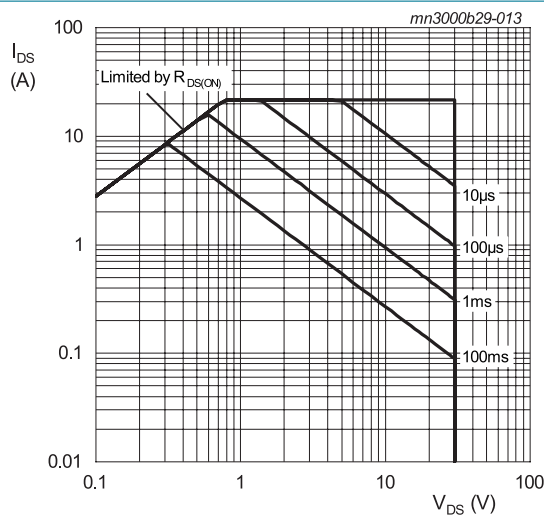
$V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}$

Fig. 11. Capacitances as a function of drain-source voltage; typical values



$V_{GS} = 0\text{ V}$

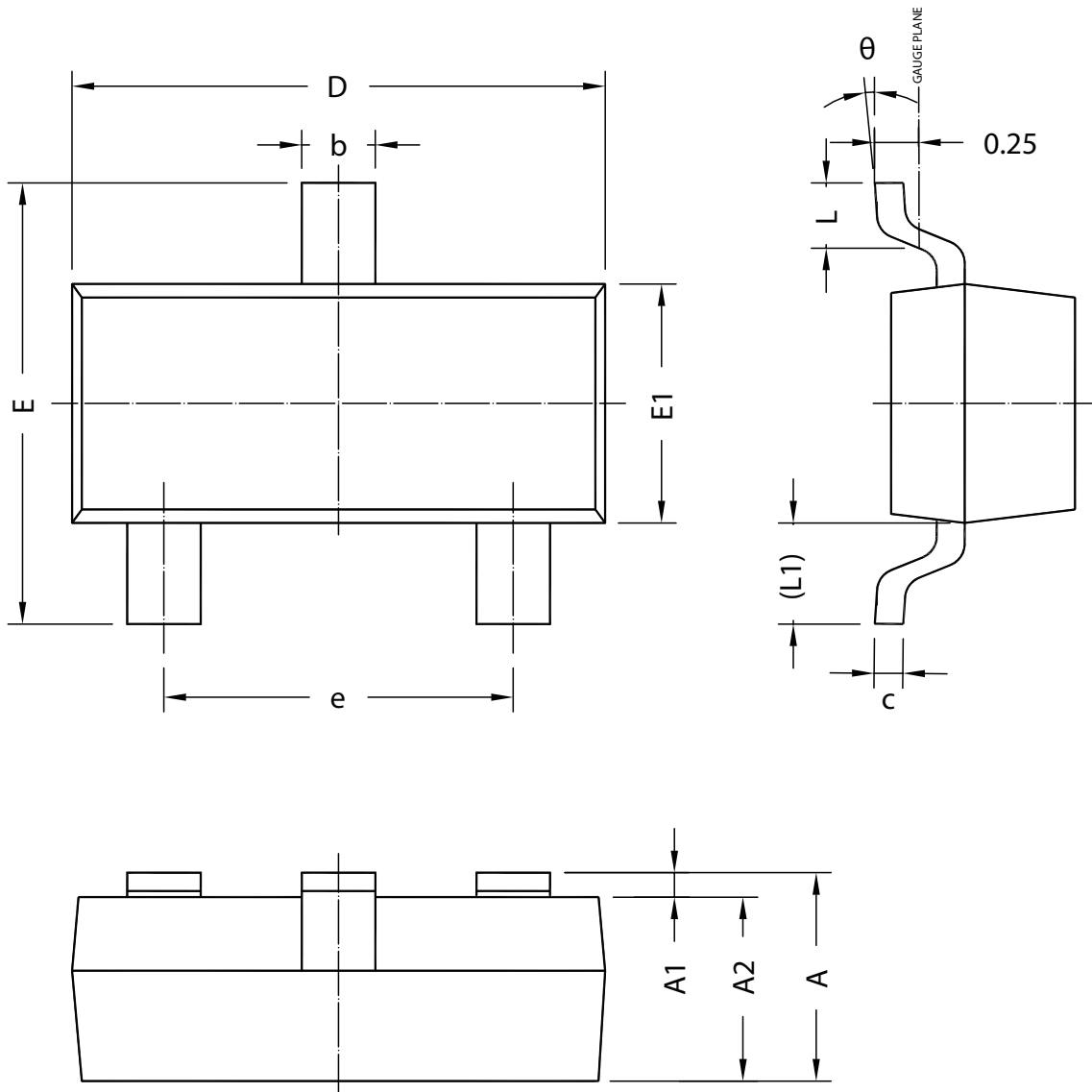
Fig 12. Source current as a function of source-drain voltage; typical values



$T_a = 25\text{ °C}$

Fig 13. Safe operating area

11. Package outline



UNIT	A	A1	A2	b	c	D	E	E1	e	L	L1	
mm	Min	0.90	0.00	0.90	0.30	0.13	2.80	2.25	1.20	1.80	0.30	0°
	Max	1.20	0.10	1.10	0.50	0.20	3.00	2.55	1.40	2.00	(0.55)	8°

Note:
1. All dimensions don't include mold flash and metal protrusion.

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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